

BAT54XY

Schottky barrier quadruple diode in very small SOT363 package

Rev. 02 — 13 January 2010

Product data sheet

1. Product profile

1.1 General description

Schottky barrier quadruple diode with an integrated guard ring for stress protection. Two electrically isolated dual Schottky barrier diodes series, encapsulated in a SOT363 very small SMD plastic package.

1.2 Features

- Low forward voltage
- Ultra small SMD plastic package
- Low capacitance

1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Line termination
- Inverse-polarity protection

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_R	continuous reverse voltage		-	-	30	V
l _F	continuous forward current		-	-	200	mA
V _F	forward voltage	I _F = 10 mA; see <u>Figure 1</u>	[1] -	-	400	mV

[1] Pulse test: $t_p \le 30$ ms; $\delta \le 0.02$.



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2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Symbol
1	anode 1		
2	cathode 2	6 5 4	6 5 4
3	anode 3 / cathode 4		
4	anode 4	0	
5	cathode 3	☐1 ☐2 ☐3	本
6	cathode 1 / anode 2		1 2 3 006aaa256

3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BAT54XY	SC-88	plastic surface mounted package; 6 leads	SOT363		

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
BAT54XY	*C5

[1] * = -: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_R	continuous reverse voltage		-	30	V
I _F	continuous forward current		-	200	mA
I _{FRM}	repetitive peak forward current	$t_p \leq \text{1 s; } \delta \leq \text{0.5}$	-	300	mA
I _{FSM}	non-repetitive peak forward current	t _p < 10 ms	-	600	mA
Tj	junction temperature		-	125	°C
T _{amb}	ambient temperature		-65	+125	°C
T _{stg}	storage temperature		–65	+150	°C

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6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-s)}$	thermal resistance from junction to soldering point	in free air	<u>[1]</u> _	-	260	K/W

^[1] Soldering point at pins 2, 3, 5 and 6.

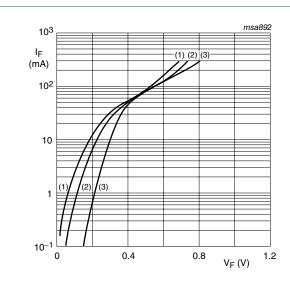
7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

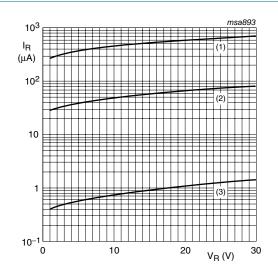
	•					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
V _F	forward voltage	see Figure 1;	<u>[1]</u>			
		$I_F = 0.1 \text{ mA}$	-	-	240	mV
		I _F = 1 mA	-	-	320	mV
		I _F = 10 mA	-	-	400	mV
		$I_F = 30 \text{ mA}$	-	-	500	mV
		I _F = 100 mA	-	-	800	mV
I _R	reverse current	V _R = 25 V; see Figure 2	-	-	2	μΑ
C_d	diode capacitance	$V_R = 1 V$; $f = 1 MHz$; see Figure 3	-	-	10	pF

^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$



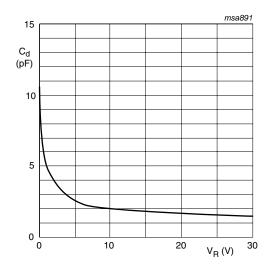
- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) T_{amb} = 25 °C

Fig 1. Forward current as a function of forward voltage; typical values



- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) T_{amb} = 25 °C

Fig 2. Reverse current as a function of reverse voltage; typical values



 T_{amb} = 25 °C; f = 1 MHz

Fig 3. Diode capacitance as a function of reverse voltage; typical values

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8. Package outline

Plastic surface-mounted package; 6 leads

SOT363

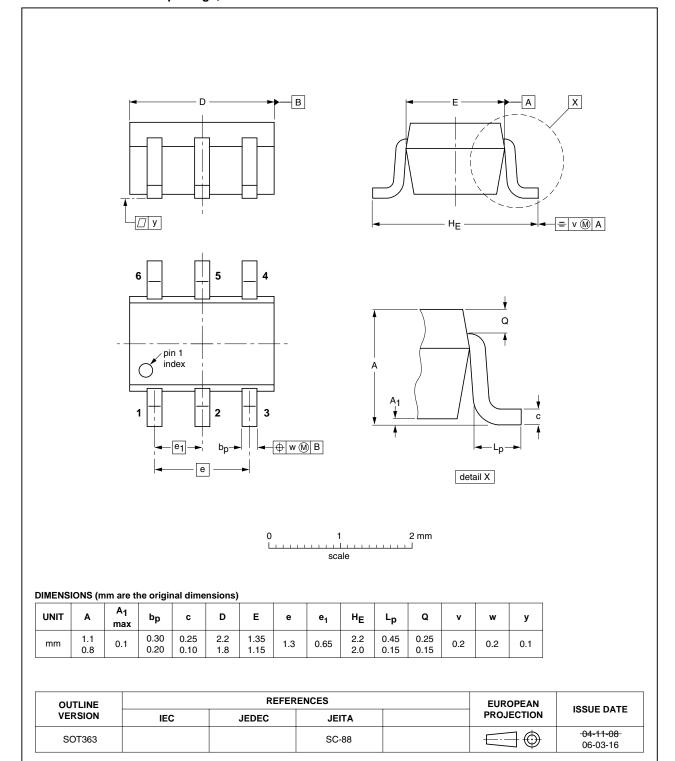


Fig 4. Package outline SOT363 (SC-88)

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Packing information

Table 8. **Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description		Packing q	uantity
				3000	10000
BAT54XY	SOT363	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-165

^[1] For further information and the availability of packing methods, see <u>Section 12</u>.

^[2] T1: normal taping

^[3] T2: reverse taping



10. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAT54XY_2	20100113	Product data sheet	-	BAT54XY_1
Modifications:		eet was changed to reflect w legal definitions and disc		
	• Table 2 "Pin	ning": updated		
	 Figure 4 "Pa 	ckage outline SOT363 (SC	:-88)": updated	
BAT54XY_1	20050117	Product data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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